SLG59M1495V



Ultra-small 80 m Ω , 1.0 A Load Switch with Discharge

General Description

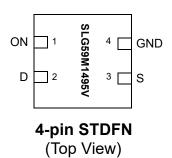
The SLG59M1495V is designed for load switching applications. The part comes with one 80 m Ω 1.0 A rated MOSFET controlled by a single ON control pin. The MOSFET's ramp rate is adjustable depending on the input current level of the ON pin.

The product is packaged in an ultra-small 1.0 x 1.0 mm package.

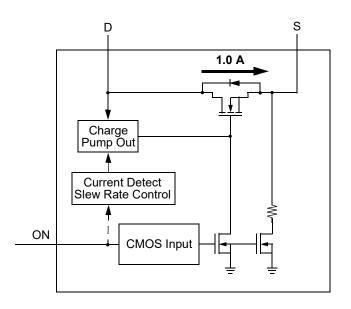
Features

- One 80 m Ω 1.0 A MOSFET
- One integrated VGS Charge Pump
- User selectable ramp rate with external resistor
- Integrated Discharge Resistor
- Over Temperature Protection
- Pb-Free / Halogen-Free / RoHS compliant
- STDFN 4L, 1.0 x 1.0 x 0.55 mm

Pin Configuration



Block Diagram





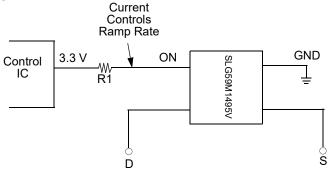
Pin Description

Pin #	Pin Name	Туре	Pin Description
1	ON	Input	Turns on MOSFET. Configurable slew rate control depending on input current.
2	D	MOSFET	Drain of Power MOSFET
3	S	MOSFET	Source of Power MOSFET
4	GND	GND	Ground

Ordering Information

Part Number	Туре	Production Flow		
SLG59M1495V	STDFN 4L	Extended Commercial, -20 °C to 70 °C		
SLG59M1495VTR	STDFN 4L (Tape and Reel)	Extended Commercial, -20 °C to 70 °C		

Application Diagram



Adjustable Ramp Rate vs. ON Pin Current (5.5 V, 25 °C)

I_ON	T _{SLEW} (typ)
20 µA	0.56 V/ms
50 μA	1.34 V/ms
100 μA	2.53 V/ms
150 μA	3.71 V/ms
200 µA	4.68 V/ms
250 μΑ	5.63 V/ms

Adjustable Slew Rate (ON Pin 2)

SLG59M1495V has a built in configurable slew control feature. The configurable slew control uses current detection method on Pin 2. When ON voltage rise above ON_VIH_INI (1.2 V typical), the slew control circuit will measure the current flowing into Pin 2. Based on the current flowing into pin 2, different slew rates will be selected by the internal control circuit. See I_ON vs. Tslew table on page 2. The slew rate is configurable by selecting a different R1 resistor value as shown on application diagram on page 2. Calculating the R1 value depends on both the desired slew rate, and the VOH level of the device driving the ON Pin 2.

ON_Current = (GPIO_VOH - ON_VREF (1.05 V typical)) / R1



Absolute Maximum Ratings

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
V _D	Power Supply				6	V
Τ _S	Storage Temperature		-65		150	°C
ESD _{HBM}	ESD Protection	Human Body Model	2000			V
ESD _M	ESD Protection	Machine Model	400			V
MSL	Moisture Sensitivity Level				1	
W _{DIS}	Package Power Dissipation				0.5	W
NOSFET IDS _{PK}	Peak Current from Drain to Source	For no more than 1 ms with 1% duty cycle			1.5	Α

Note: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics

T _A = -20 to 7	0 °C (unless	otherwise stated)
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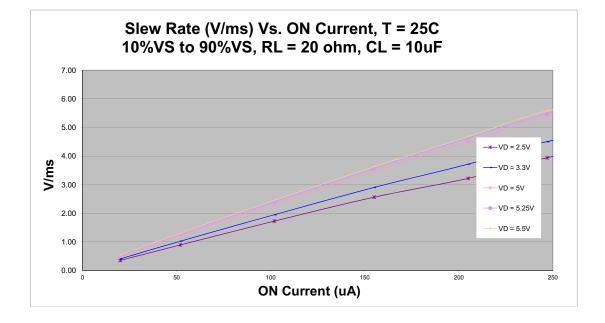
Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
V _D	Power Supply Voltage	-20 to 70°C	2.5		5.5	V
I	Bower Sweek Correct (DIN 2)	when OFF		0.1	1	μΑ
I _{DD}	Power Supply Current (PIN 2)	when ON, No load		18	30	μA
PDC	Static Drain to Source	T _A 25°C MOSFET		80	100	mΩ
RDS _{ON}	ON Resistance	T _A 70°C MOSFET		100	110	mΩ
IDS	Operating Current	V _D = 2.5 V to 5.5 V			1.0	Α
T _{Delay_ON}	ON pin Delay Time	50% ON to Ramp Begin Input Current (PIN 1) = 20 μ A, V _D = 5 V, Source_Cap = 10 μ F, R _L = 20 Ω	0	2.4	4.0	ms
		50% ON to 90% V _S	С	onfigurable	1	ms
T _{Total_ON}	Total Turn On Time	Example: Input Current (PIN 1) = 20 μ A, V _D = 5 V, Source_Cap = 10 μ F, R _L = 20 Ω		11.7		ms
		10% V _S to 90% V _S	Configurable ¹			V/ms
T _{SLEWRATE}	Slew Rate	Example: Input Current (PIN 1) = 20 μ A, V _D = 5 V, Source_Cap = 10 μ F, R _L = 20 Ω		0.56		V/ms
R _{DIS}	Discharge Resistance		100	150	300	Ω
ON_V_{REF}	ON Pin Reference Voltage ²		0.99	1.05	1.10	V
ON_V _{IH_INI}	Initial Turn On Voltage	Internal Charge Pump ON	1.2		V _{DD}	V
ON_V _{IL}	Low Input Voltage on ON pin	Internal Charge Pump OFF	-0.3	0	0.3	V
ON_R	Input Impedance on ON pin		100			MΩ
THERMON	Thermal shutoff turn-on temperature			120		°C
THERMOFF	Thermal shutoff turn-off temperature			100		°C
THERM _{TIME}	Thermal shutoff time				1	ms
T _{Delay_OFF}	OFF Delay Time	50% ON to V _S Fall, V _D = 5 V, R_L = 20 Ω , no C _L		6.5	20	μs
T _{FALL}	V _S Fall Time	90% V _S to 10% V _S , V _D = 5 V, R _L = 20 Ω, no C _L		1.2	2	μs

1. Refer to table for configuration details.

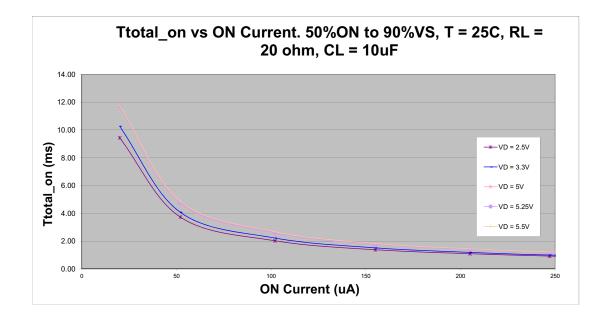
2. Voltage before ON pin resistor needs to be higher than 1.2 V to generate required I_{ON}



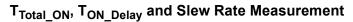
Slew Rate vs. ON Current

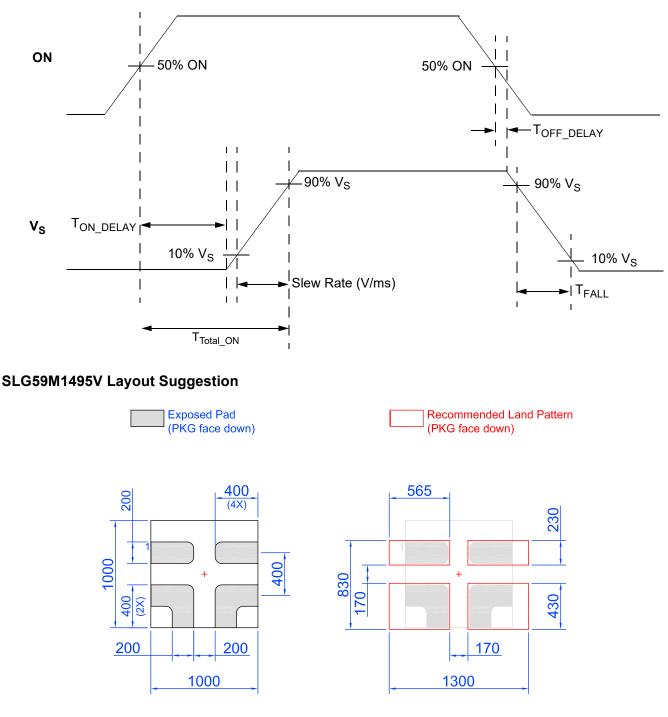


T_{Total ON} vs. On Current





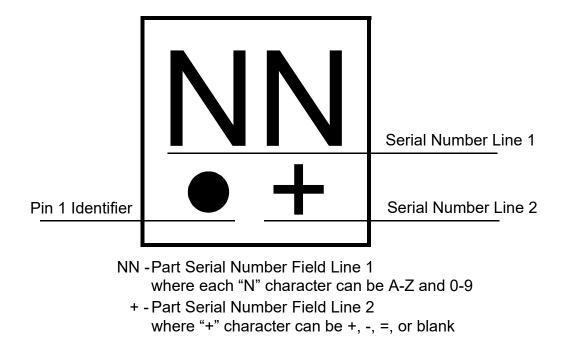




Note: All dimensions shown in micrometers (µm)



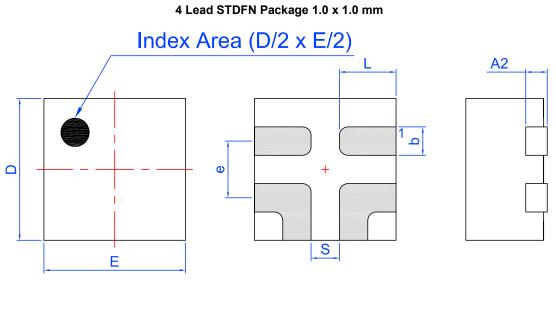
Package Top Marking System Definition





SLG59M1495V

Package Drawing and Dimensions





Unit: mm Symbol Min Nom. Symbol Min Max Nom. Max 0.55 0.60 1.00 1.05 Α 0.50 D 0.95 **A1** 0.005 -0.060 Е 0.95 1.00 1.05 0.15 A2 0.10 0.20 L 0.35 0.40 0.45 0.2 REF 0.20 b 0.15 0.25 S 0.40 BSC е

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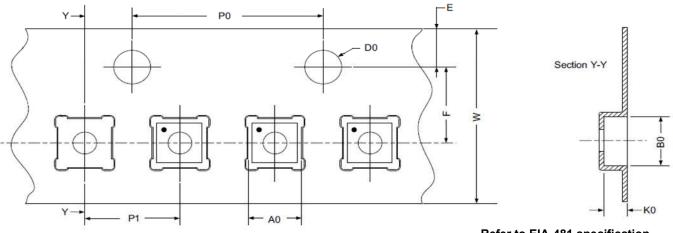


Tape and Reel Specifications

Dookogo	# of	Nominal Max Units		Reel &	Leader (min)		Trailer (min)		Таре	Part	
Package Type	# of Pins	Package Size [mm]	per Reel		Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STDFN 4L Green	4	1.0 x 1.0 x 0.55	8000	8000	178 / 60	200	400	200	400	8	2

Carrier Tape Drawing and Dimensions

Package Type	PocketBTM Length	PocketBTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge		Tape Width
	A0	В0	K0	P0	P1	D0	E	F	w
STDFN 4L Green	1.16	1.16	0.63	4	2	1.5	1.75	3.5	8



Refer to EIA-481 specification

Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 0.55 mm³ (nominal). More information can be found at www.jedec.org.



Revision History

Date	Version	Change
		Updated Company name and logo Fixed typos
11/20/2017	1.03	Updated Package Marking Definition Updated Layout Suggestion
11/30/2015	1.02	Added MSL information
9/9/2015	1.01	Updated Abs Max Ratings with ESD for Machine Model Updated Conditions in Electrical Characteristics Table

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